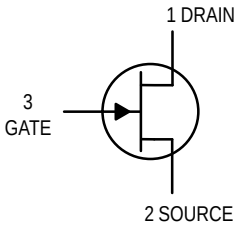
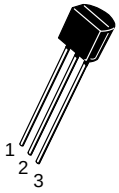
JFET VHF/UHF Amplifiers

N–Channel — Depletion



2N5484
2N5486



CASE 29–04, STYLE 5
TO–92 (TO–226AA)

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain–Gate Voltage	V_{DG}	25	Vdc
Reverse Gate–Source Voltage	V_{GSR}	25	Vdc
Drain Current	I_D	30	mAdc
Forward Gate Current	$I_{G(f)}$	10	mAdc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	350 2.8	mW mW/°C
Operating and Storage Junction Temperature Range	T_J, T_{stg}	–65 to +150	°C

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic		Symbol	Min	Typ	Max	Unit
OFF CHARACTERISTICS						
Gate–Source Breakdown Voltage (I_G = –1.0 μAdc, V_{DS} = 0)		$V_{(BR)GSS}$	–25	—	—	Vdc
Gate Reverse Current		I_{GSS}				
(V_{GS} = –20 Vdc, V_{DS} = 0)			—	—	–1.0	nAdc
(V_{GS} = –20 Vdc, V_{DS} = 0, T_A = 100°C)			—	—	–0.2	μAdc
Gate Source Cutoff Voltage		$V_{GS(off)}$				Vdc
(V_{DS} = 15 Vdc, I_D = 10 nAdc)	2N5484		–0.3	—	–3.0	
	2N5486		–2.0	—	–6.0	
ON CHARACTERISTICS						
Zero–Gate–Voltage Drain Current	2N5484	I_{DSS}	1.0	—	5.0	mAdc
(V_{DS} = 15 Vdc, V_{GS} = 0)	2N5486		8.0	—	20	
SMALL–SIGNAL CHARACTERISTICS						
Forward Transfer Admittance		$\lvert y_{fs} \rvert$				μmhos
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 kHz)	2N5484		3000	—	6000	
	2N5486		4000	—	8000	
Input Admittance		$Re(y_{is})$				μmhos
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 100 MHz)	2N5484		—	—	100	
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 400 MHz)	2N5486		—	—	1000	
Output Admittance		$\lvert y_{os} \rvert$				μmhos
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 kHz)	2N5484		—	—	50	
	2N5486		—	—	75	
Output Conductance		$Re(y_{os})$				μmhos
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 100 MHz)	2N5484		—	—	75	
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 400 MHz)	2N5486		—	—	100	
Forward Transconductance		$Re(y_{fs})$				μmhos
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 100 MHz)	2N5484		2500	—	—	
(V_{DS} = 15 Vdc, V_{GS} = 0, f = 400 MHz)	2N5486		3500	—	—	

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted) (Continued)

Characteristic		Symbol	Min	Typ	Max	Unit
SMALL–SIGNAL CHARACTERISTICS (continued)						
Input Capacitance (V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 MHz)		C_{iss}	—	—	5.0	pF
Reverse Transfer Capacitance (V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 MHz)		C_{rss}	—	—	1.0	pF
Output Capacitance (V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 MHz)		C_{oss}	—	—	2.0	pF
FUNCTIONAL CHARACTERISTICS						
Noise Figure		NF				dB
(V_{DS} = 15 Vdc, V_{GS} = 0, R_G = 1.0 Megohm, f = 1.0 kHz)			—	—	2.5	
(V_{DS} = 15 Vdc, I_D = 1.0 mAdc, $R_G \approx$ 1.0 kΩ, f = 100 MHz)	2N5484		—	—	3.0	
(V_{DS} = 15 Vdc, I_D = 1.0 mAdc, $R_G \approx$ 1.0 kΩ, f = 200 MHz)	2N5484		—	4.0	—	
(V_{DS} = 15 Vdc, I_D = 4.0 mAdc, $R_G \approx$ 1.0 kΩ, f = 100 MHz)	2N5486		—	—	2.0	
(V_{DS} = 15 Vdc, I_D = 4.0 mAdc, $R_G \approx$ 1.0 kΩ, f = 400 MHz)	2N5486		—	—	4.0	
Common Source Power Gain		G_{ps}				dB
(V_{DS} = 15 Vdc, I_D = 1.0 mAdc, f = 100 MHz)	2N5484		16	—	25	
(V_{DS} = 15 Vdc, I_D = 1.0 mAdc, f = 200 MHz)	2N5484		—	14	—	
(V_{DS} = 15 Vdc, I_D = 4.0 mAdc, f = 100 MHz)	2N5486		18	—	30	
(V_{DS} = 15 Vdc, I_D = 4.0 mAdc, f = 400 MHz)	2N5486		10	—	20	

POWER GAIN

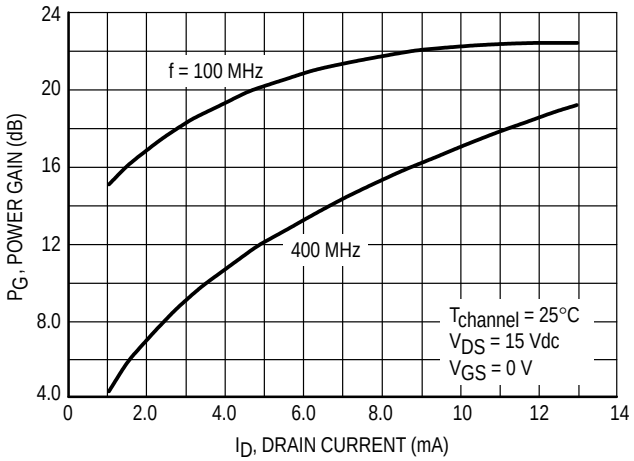
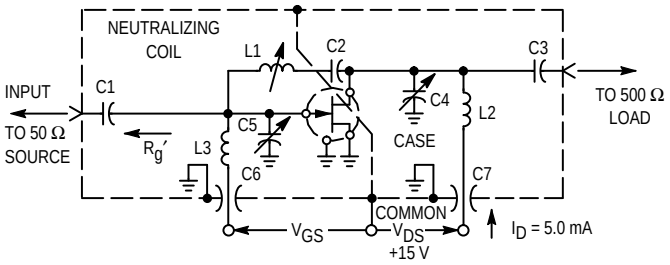


Figure 1. Effects of Drain Current



Adjust V_{GS} for
I_D = 50 mA
V_{GS} < 0 Volts

NOTE: The noise source is a hot–cold body (AIL type 70 or equivalent) with a test receiver (AIL type 136 or equivalent).

Reference Designation	VALUE	
	100 MHz	400 MHz
C1	7.0 pF	1.8 pF
C2	1000 pF	17 pF
C3	3.0 pF	1.0 pF
C4	1–12 pF	0.8–8.0 pF
C5	1–12 pF	0.8–8.0 pF
C6	0.0015 μF	0.001 μF
C7	0.0015 μF	0.001 μF
L1	3.0 μH*	0.2 μH**
L2	0.15 μH*	0.03 μH**
L3	0.14 μH*	0.022 μH**

*L1 17 turns, (approx. — depends upon circuit layout) AWG #28 enameled copper wire, close wound on 9/32″ ceramic coil form. Tuning provided by a powdered iron slug.
L2 4–1/2 turns, AWG #18 enameled copper wire, 5/16″ long, 3/8″ I.D. (AIR CORE).
L3 3–1/2 turns, AWG #18 enameled copper wire, 1/4″ long, 3/8″ I.D. (AIR CORE).

**L1 6 turns, (approx. — depends upon circuit layout) AWG #24 enameled copper wire, close wound on 7/32″ ceramic coil form. Tuning provided by an aluminum slug.
L2 1 turn, AWG #16 enameled copper wire, 3/8″ I.D. (AIR CORE).
L3 1/2 turn, AWG #16 enameled copper wire, 1/4″ I.D. (AIR CORE).

Figure 2. 100 MHz and 400 MHz Neutralized Test Circuit

NOISE FIGURE
($T_{channel}$ = 25°C)

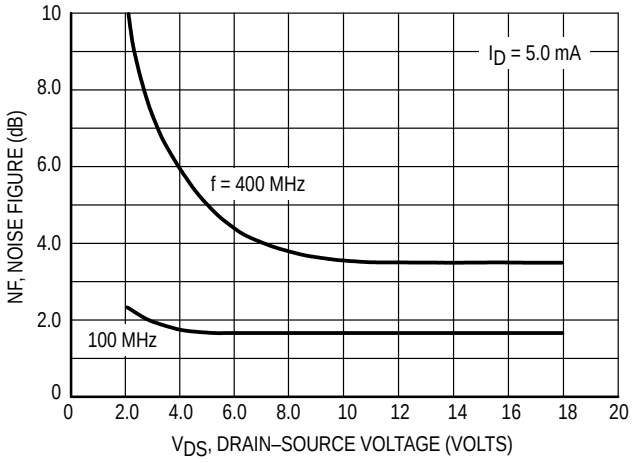


Figure 3. Effects of Drain–Source Voltage

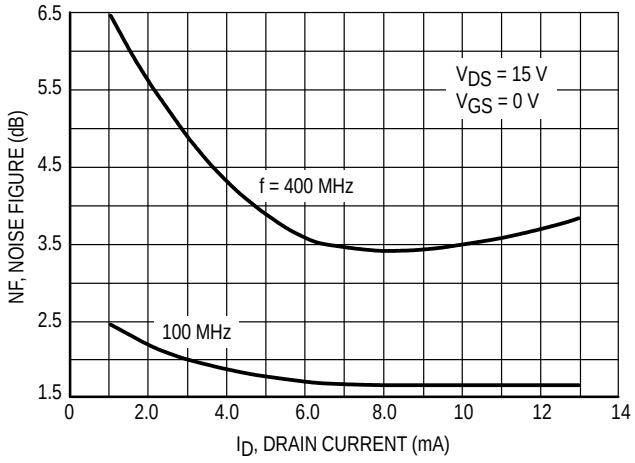


Figure 4. Effects of Drain Current

INTERMODULATION CHARACTERISTICS

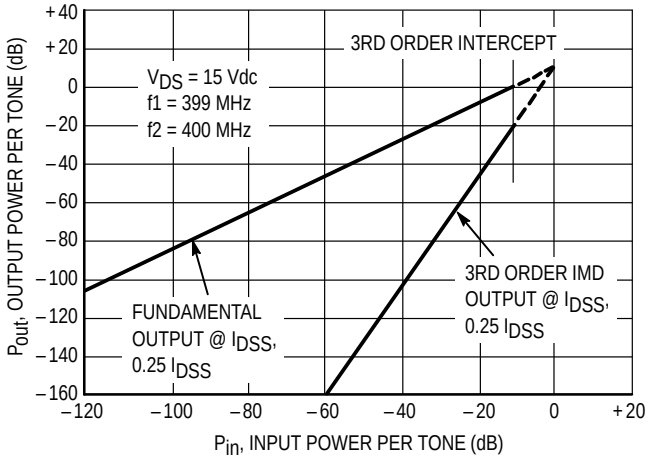


Figure 5. Third Order Intermodulation Distortion

COMMON SOURCE CHARACTERISTICS

ADMITTANCE PARAMETERS

(V_{DS} = 15 Vdc, $T_{channel}$ = 25°C)

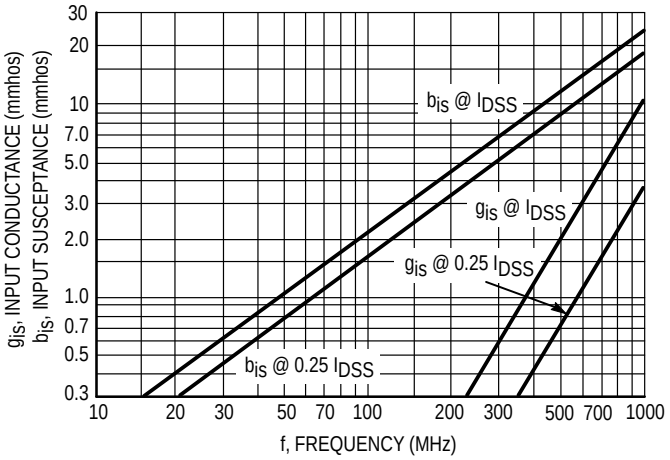


Figure 6. Input Admittance (y_{is})

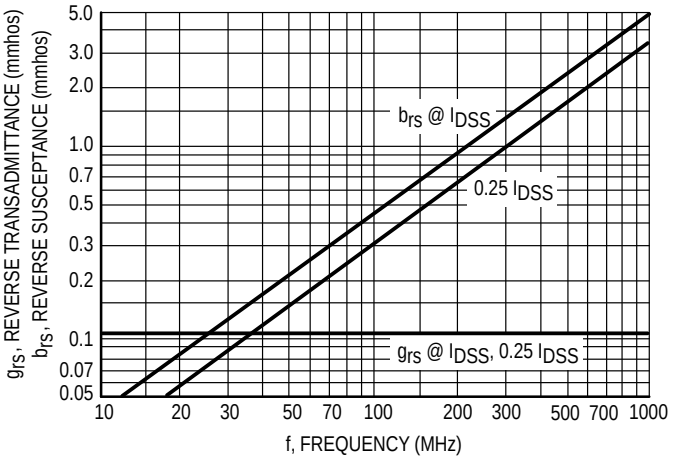


Figure 7. Reverse Transfer Admittance (y_{rs})

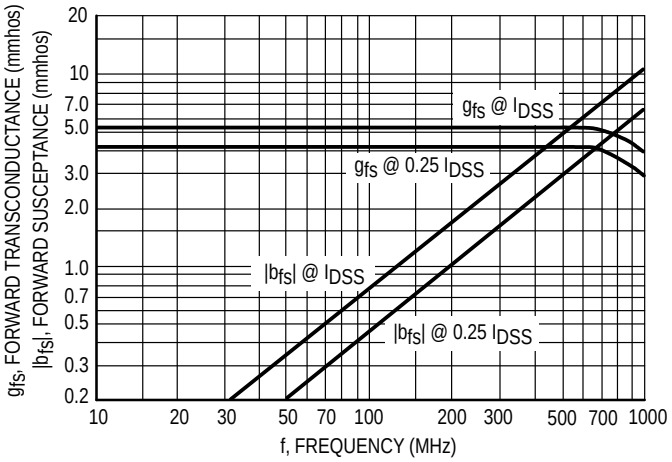


Figure 8. Forward Transadmittance (y_{fs})

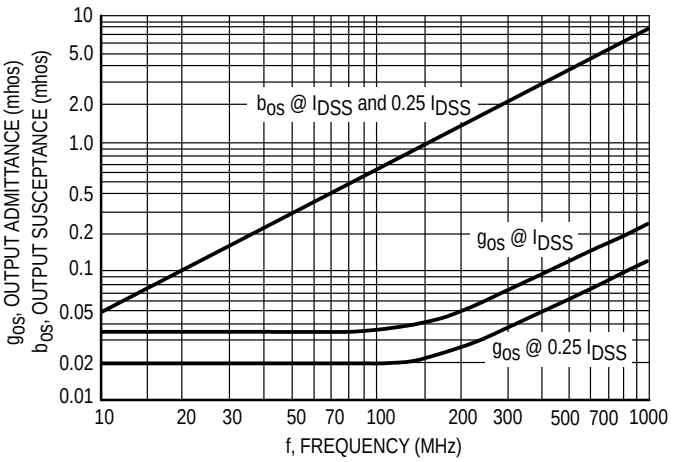


Figure 9. Output Admittance (y_{os})

COMMON SOURCE CHARACTERISTICS

S–PARAMETERS

(V_{DS} = 15 Vdc, $T_{channel}$ = 25°C, Data Points in MHz)

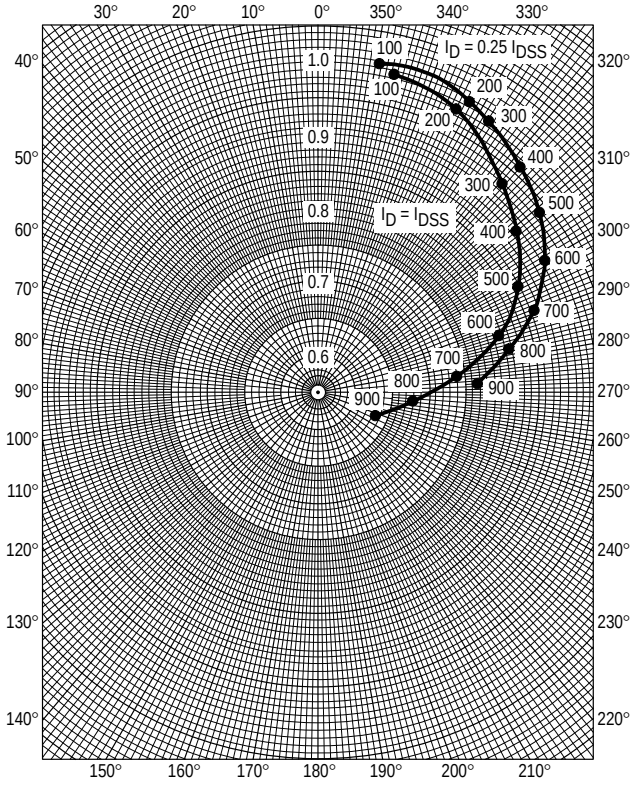


Figure 10. S_{11s}

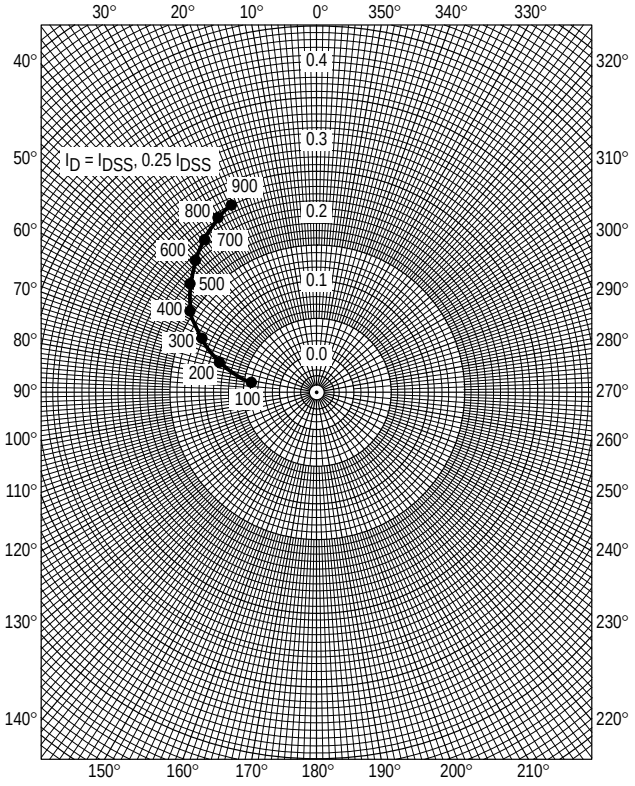


Figure 11. S_{12s}

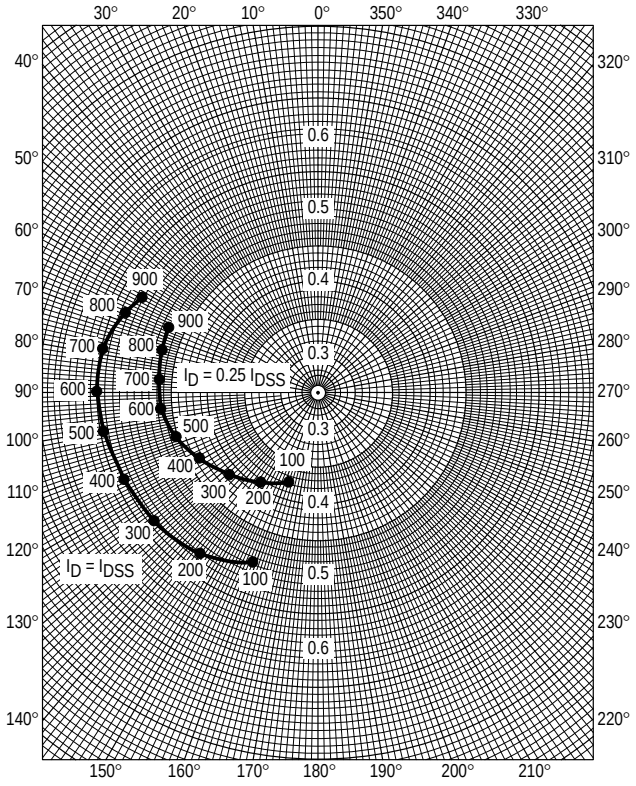


Figure 12. S_{21s}

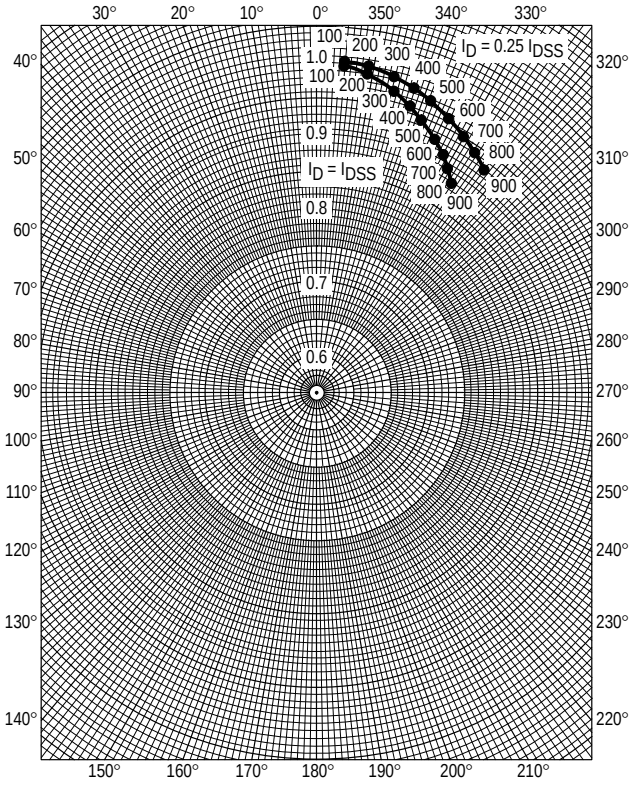


Figure 13. S_{22s}

COMMON GATE CHARACTERISTICS

ADMITTANCE PARAMETERS

(V_{DG} = 15 Vdc, $T_{channel}$ = 25°C)

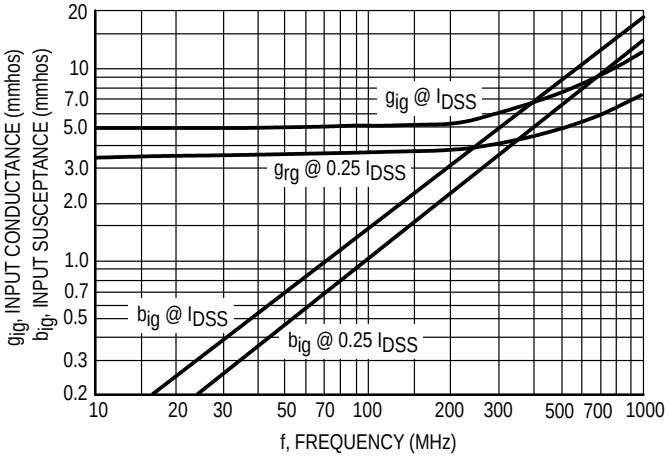


Figure 14. Input Admittance (y_{ig})

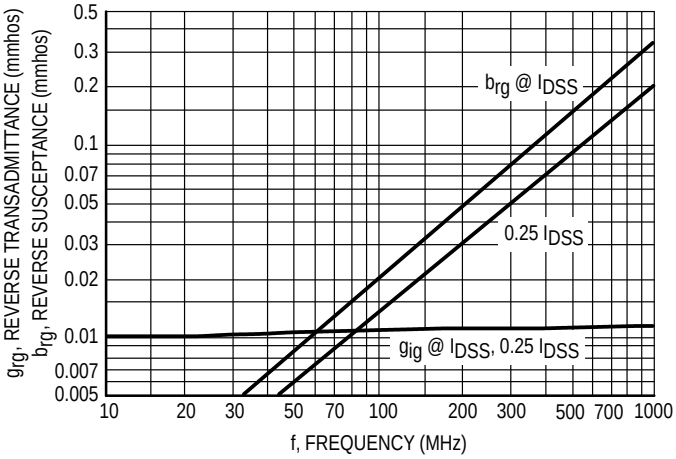


Figure 15. Reverse Transfer Admittance (y_{rg})

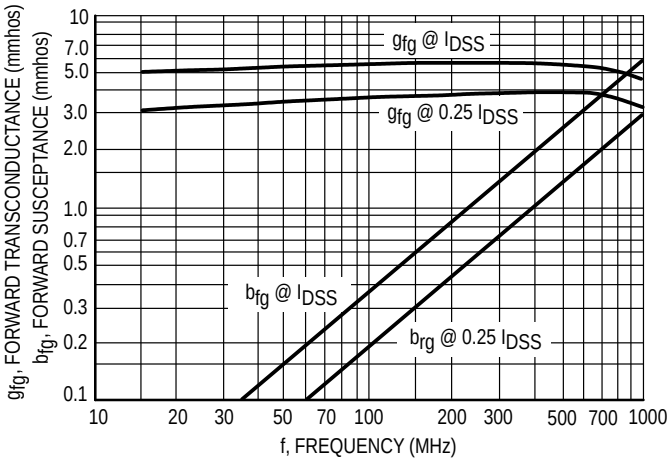


Figure 16. Forward Transfer Admittance (y_{fg})

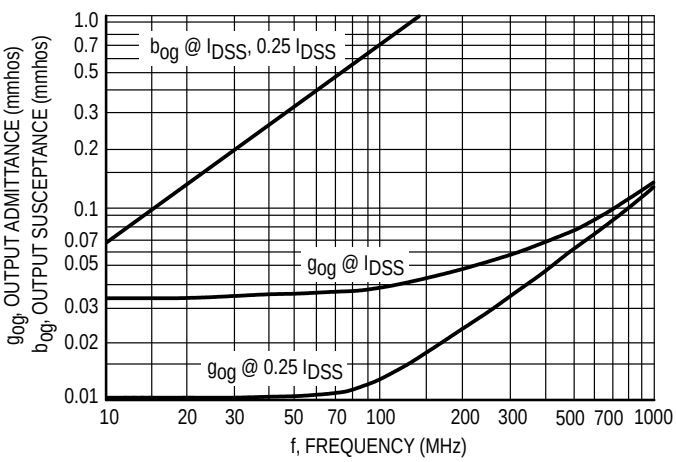


Figure 17. Output Admittance (y_{og})

COMMON GATE CHARACTERISTICS

S–PARAMETERS

(V_{DS} = 15 Vdc, $T_{channel}$ = 25°C, Data Points in MHz)

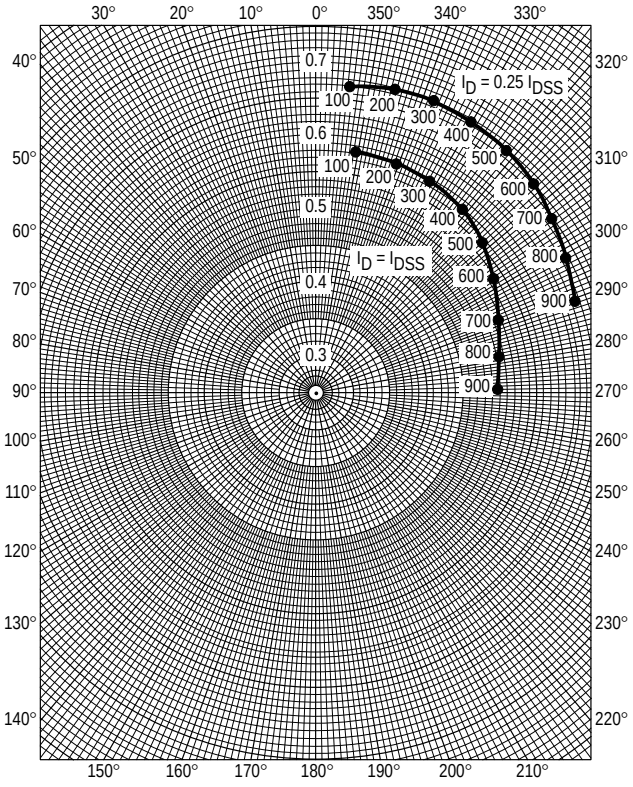


Figure 18. S_{11g}

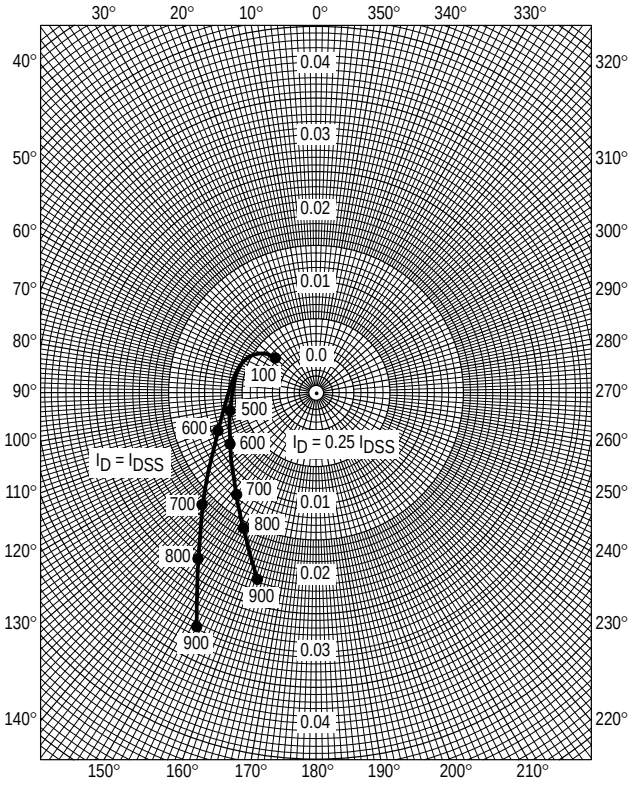


Figure 19. S_{12g}

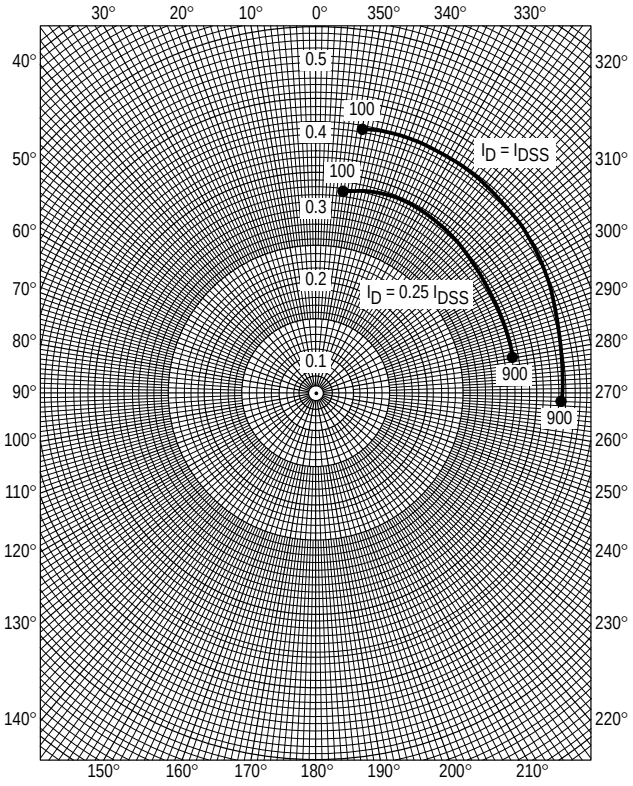


Figure 20. S_{21g}

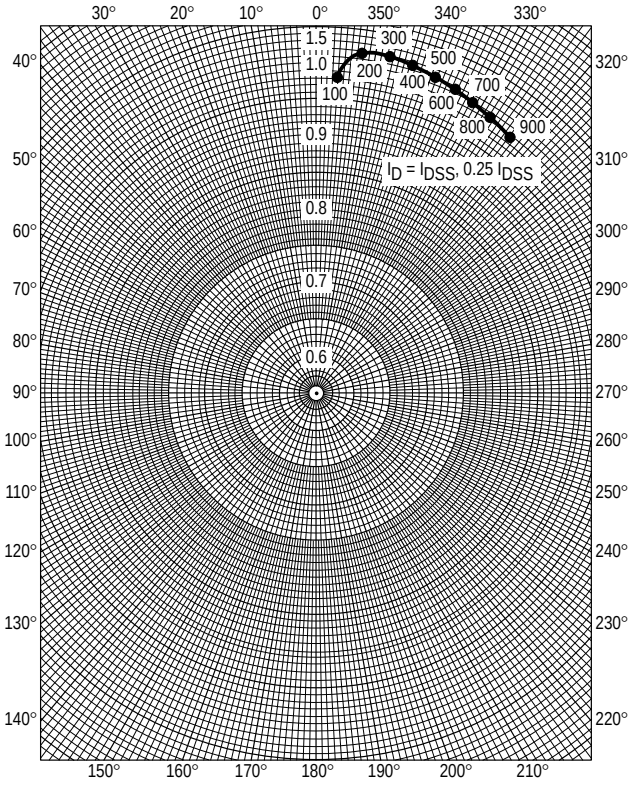
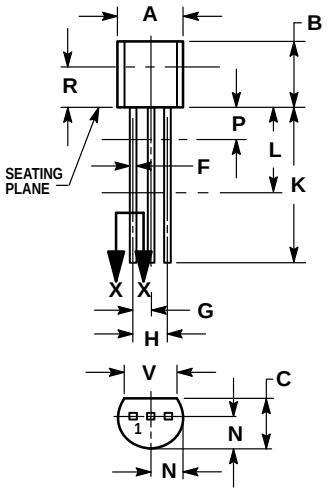
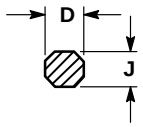


Figure 21. S_{22g}

PACKAGE DIMENSIONS





SECTION X–X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. DIMENSION F APPLIES BETWEEN P AND L. DIMENSION D AND J APPLY BETWEEN L AND K MINIMUM. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.022	0.41	0.55
F	0.016	0.019	0.41	0.48
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	—	12.70	—
L	0.250	—	6.35	—
N	0.080	0.105	2.04	2.66
P	—	0.100	—	2.54
R	0.115	—	2.93	—
V	0.135	—	3.43	—

CASE 029–04
(TO–226AA)
ISSUE AD

STYLE 5:
PIN 1. DRAIN
2. SOURCE
3. GATE

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